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ZHOU BING

ZHOU BING

9.67285% 4.76425% 5,561 2,739

	2000	57.7484%	2000	57.7484%
ZHOU BING	670	19.3457%	335	9.67285%
	330	9.5285%	165	4.76425%
	463.2994	13.3774%	963.2994	27.8145%

91361100MA386PNW9N

ZHOU BING

	2,000	57.75%
ZHOU BING	670	19.35%
	463.2994	13.38%
	330	9.53%
	3463	100.00%

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	-3,592,235.52	-13,548,596.96
	-3,369,309.31	-13,403,072.37

	2000	57.7484%
ZHOU BING	670	19.3457%
	330	9.5285%
	463.2994	13.3774%
	3463.2994	100.0%

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ZHOU BING 545****10

ZHOU BING

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ZHOU BING

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5,561

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	2000	2000	57.7484%
ZHOU BING	670	670	19.3457%
	330	330	9.5285%
	463.2994	463.2994	13.3774%
	3463.2994	3463.2994	100%

2.6

	2000	2000	57.7484%
ZHOU BING	335	335	9.67285%
	165	165	4.76425%
	963.2994	963.2994	27.8145%
	3463.2994	3463.2994	100%

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